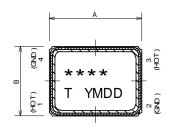
for Analog Devices

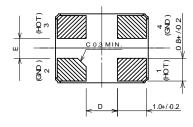
1. Specification

No.	Parameters	Requirements		
1	Package type	TSX-3225		
2	Nominal frequency	40.00000MHz		
3	Mode of vibration	AT-cut / Fundamental		
4	Storage temp. range	-40 to +85degC		
5	Operating temp. range	-30 to +85degC		
6	Frequency tolerance	+/-10.0 ppm max. at 25+/-2deg.C		
7	Frequency stability	+/-15.0 ppm max. (-30 to +85degC, Ref. 25degC)		
8	Resonance resistance	40.0 ohm max.		
9	Load capacitance	10.0 pF		
10	Drive level	0.1mW max.		
11	Aging(over 1 year at 25degC)	+/-2.0 ppm max.		
12	Insulation resistance	500 M ohms min. / DC 100V +/- 15V		

2. Dimension and Marking (Example)







[LAND PATTERN]

Size in mm

Marking

A	В	С	D	E
3.20	2.50	0.60	1.00	0.70
+/-0.15	+/-0.15	max.	+/-0.20	+/-0.20

Description

Laser marking ET's ID (4 digits)

ET Mark (T)

Package Lot No. (4 digits)

Lid :KOVAR, Y: the last 1 digit of year

> Electrolytic Ni plating M: 1 digit of month

Base :Ceramic, W+Ni+Au plated (Jan to Sept; 1 to 9, Oct; X, Nov; Y, Dec; Z)

Seal :Seam Weld, N2 gas DD: 2 digits of day

DRAW: A. Inoshita 2006/1/19

CHK'D: Y. Kawaguchi

APP: J. Kusano

Design Department/Crystal Unit Grp.

Development & Design Management Division

EPSON TOYOCOM CORPORATION